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Nota di contenuto

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Sommario/riassunto

The development of power semiconductors with greater ratings and improved characteristics has meant that the power industry has become more willing to develop new converter configurations. These new configurations take advantage of the higher controllability and switching frequencies of the new devices. The next few years will decide which of the proposed technologies will dominate future power transmission systems. Flexible Power Transmission is a comprehensive guide to the high voltage direct current (HVDC) options available, helping the reader to make informed decisions for desi

